

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	33	(randy near hoffman) and (tft)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/20 14:14
L2	18	(randy near hoffman) and (tft) and (channel near10 (dope or doping or doped))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/20 14:23
L3	18	(randy near hoffman) and (tft) and (channel near10 (dope or doping or doped or dopant))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/20 14:15
L4	2	(randy near hoffman) and (tft) and (channel with (dope or doping or doped or dopant)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/20 14:16
L5	2263	(tft or (thin near film near transistor)) and (channel near10 (deposit or depositing or deposited or deposition))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/20 14:24
L6	275	(tft or (thin near film near transistor)) same (channel near10 (deposit or depositing or deposited or deposition)) same (dope or doping or doped or dopant)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/20 14:25
L7	16	(tft or (thin near film near transistor)) same (channel near10 (deposit or depositing or deposited or deposition)) same (dope or doping or doped or dopant) same threshold same gate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/20 14:26
L8	4	(tft or (thin near film near transistor)) same (channel near2 (deposit or depositing or deposited or deposition)) same (dope or doping or doped or dopant) same threshold same gate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/20 14:26

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L9	7	(tft or (thin near film near transistor)) same (channel near5 (deposit or depositing or deposited or deposition)) same (dope or doping or doped or dopant) same threshold same gate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/20 14:28
L10	41864	(tft or (thin near film near transistor)) and (channel near5 (deposit or depositing or deposited or deposition)) same (dope or doping or doped or dopant) same (threshold near5 gate)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/20 14:28
L11	1	(tft or (thin near film near transistor)) and (channel near5 (deposit or depositing or deposited or deposition)) same (dope or doping or doped or dopant) same (threshold near5 gate)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/20 14:28
L12	229	(tft or (thin near film near transistor)) and (channel near5 (deposit or depositing or deposited or deposition)) and (dope or doping or doped or dopant) and (threshold near5 gate)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/20 14:29
L13	5	(tft or (thin near film near transistor)) and (channel near5 (deposit or depositing or deposited or deposition)) and (dope or doping or doped or dopant) and ((dope or doping or doped or dopant) with threshold near5 gate)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/20 14:32
L43	3	(257/59.ccls. or 257/72.ccls. or 257/347.ccls. or 257/348.ccls.) and (tft or (thin near film near transistor)) and (channel near5 (deposit or depositing or deposited or deposition)) and (dope or doping or doped or dopant) and ((dope or doping or doped or dopant) with threshold near5 gate)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/20 14:33

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L44	3	(257/59.ccls. or 257/72.ccls. or 257/347.ccls. or 257/348.ccls.) and (tft or (thin near film near transistor)) and (channel near5 (deposit or depositing or deposited or deposition)) and ((dope or doping or doped or dopant) with threshold near5 gate)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/06/20 14:34
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